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Hyperfast Rectifier, 30 A FRED Pt® G5



| PRIMARY CHARACTERISTICS | | | | |
|--|-------------|--|--|--|
| I _{F(AV)} | 30 A | | | |
| V _R | 600 V | | | |
| V _F at I _F at 125 °C | 1.3 V | | | |
| t _{rr} (typ.) | 22 | | | |
| I _{FSM} | 310 | | | |
| T _J max. | 175 °C | | | |
| Package | TO-247AD 2L | | | |
| Circuit configuration | Single | | | |

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off



• 175 °C maximum operating junction temperature

Polyimide passivation

 Material categorization: for definitions of compliance please see www.vishav.com/doc?99912



ROHS COMPLIANT HALOGEN FREE

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications.

| ABSOLUTE MAXIMUM RATINGS | | | | |
|--|-----------------------------------|---|-------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Repetitive peak reverse voltage | V_{RRM} | | 600 | V |
| Average rectified forward current | I _{F(AV)} | T _C = 117 °C, D = 0.50 | 30 | |
| Non-repetitive peak surge current | I _{FSM} | $T_C = 25$ °C, $t_p = 10$ ms, sine wave | 310 | Α |
| Repetitive peak forward current | I _{FRM} | T _C = 117 °C, D = 0.50, f = 20 kHz | 60 | |
| Operating junction and storage temperature | T _J , T _{Stg} | | -55 to +175 | °C |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | |
|--|-----------------|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Breakdown voltage, blocking voltage | V_{BR}, V_{R} | I _R = 100 μA | 600 | - | =. | |
| Forward voltage | \/_ | I _F = 30 A | - | 1.6 | 2.1 | V |
| | V _F | I _F = 30 A, T _J = 125 °C | - | 1.3 | - | |
| Reverse leakage current | | V _R = V _R rated | - | - | 20 | |
| Reverse leakage current | | $T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{rated}$ | - | - | 500 | μA |
| Junction capacitance | C _T | C _T V _R = 200 V | | 36 | =. | pF |
| Series inductance | L _S | Measured to lead 5 mm from package body | - | 8 | - | nΗ |



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| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|---|---|--|--|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| | | $I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ | | - | 22 | - | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 39 | - | ns |
| | | T _J = 125 °C | | - | 50 | - | 1 |
| Dook recovery ourrent | I | T _J = 25 °C | $I_F = 20 \text{ A}$ $dI_F/dt = 1000 \text{ A/µs}$ $V_R = 400 \text{ V}$ | - | 14 | - | А |
| Peak recovery current | I _{RRM} | T _J = 125 °C | | - | 24 | - | |
| Poverse receivery charge | 0 | T _J = 25 °C | | - | 253 | - | nC |
| Reverse recovery charge | Q _{rr} | T _J = 125 °C | | - | 785 | - | IIC |
| Develope receiver times | | T _J = 25 °C | I _F = 30 A dI _F /dt = 1000 A/µs V _B = 400 V | - | 41 | - | 20 |
| Reverse recovery time | t _{rr} | T _J = 125 °C | | - | 56 | - | ns |
| Dools recovery augment | leak recovery current I _{RRM} | T _J = 25 °C | | - | 16 | - | Α |
| reak recovery current | | T _J = 125 °C | | - | 27 | - | ^ |
| Deviana vacavani abava | Reverse recovery charge Q _{rr} | T _J = 25 °C | 11 - 2-2 | - | 306 | - | nC |
| neverse recovery charge | | T _J = 125 °C | | - | 952 | - | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|-----------------------------------|-------------------------|----------|------|------------|------------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Thermal resistance, junction-to-case | R _{thJC} | | - | - | 1.1 | °C/W |
| Weight | | | - | 5.5 | - | g |
| vveigni | | | - | 0.2 | - | oz. |
| Mounting torque | | | 6 (5) | ı | 12 (10) | kgf · cm (lbf · in) |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | 175 | °C |
| Marking device | | Case style: TO-247AD 2L | | E5PX | 3006L | • |

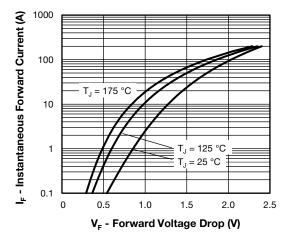


Fig. 1 - Typical Forward Voltage Drop Characteristics

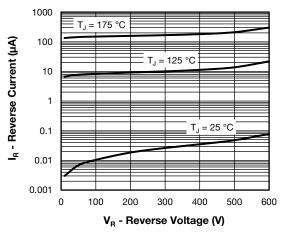


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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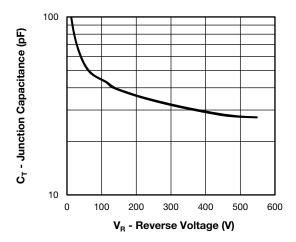


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

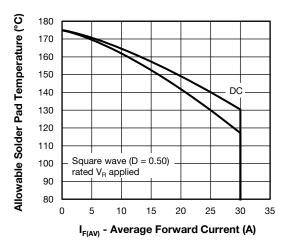


Fig. 4 - Maximum Allowable Case Temperature vs.

Average Forward Current

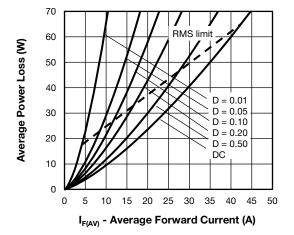


Fig. 5 - Average Power Loss vs. Average Forward Current

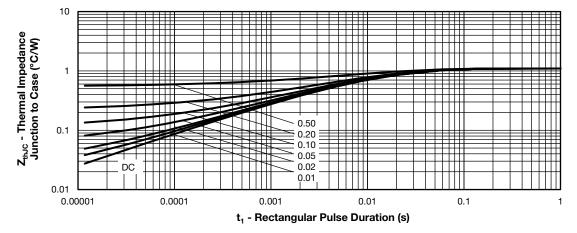


Fig. 6 - Thermal Impedance Z_{thJC} - Characteristics

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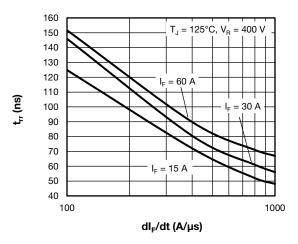


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

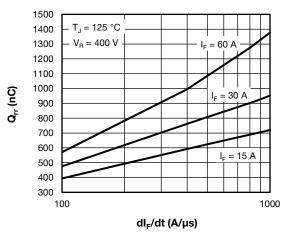


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

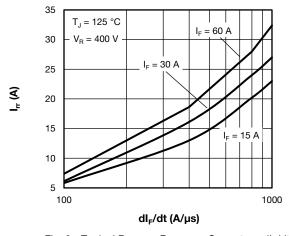


Fig. 9 - Typical Reverse Recovery Current vs. dI_F/dt

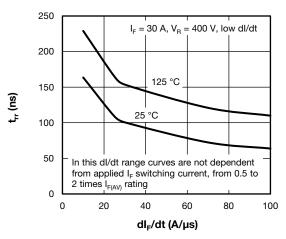


Fig. 10 - Typical Reverse Recovery Time vs. dI_E/dt

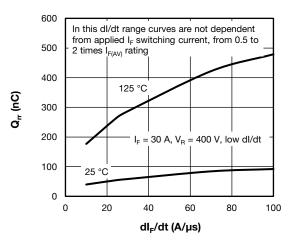


Fig. 11 - Typical Reverse Recovery Charge vs. dl_F/dt

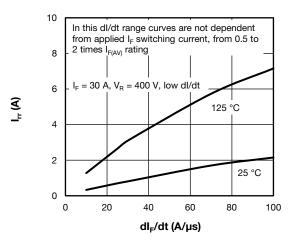


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt

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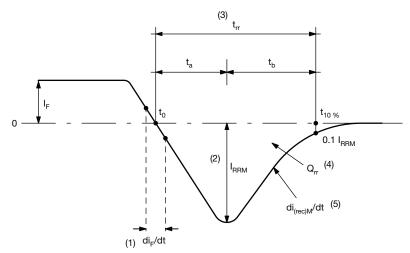


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

(1) di_F/dt - rate of change of current through zero crossing

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- (2) I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}$ $\,Q_{rr}$ area under curve defined by t_0 and $t_{10}\,\%$

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|-------------------|------------------------|-------------------------|--|--|
| PREFERRED P/N | QUANTITY PER TUBE | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | |
| VS-E5PX3006L-N3 | 25 | 500 | Antistatic plastic tube | | |

| LINKS TO RELATED DOCUMENTS | | | | |
|--|--------------------------|--|--|--|
| Dimensions <u>www.vishay.com/doc?95536</u> | | | | |
| Part marking information | www.vishay.com/doc?95648 | | | |



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